

February 1994 Revised April 1999

#### 74LCX16652

# Low Voltage Transceiver/Register with 5V Tolerant Inputs and Outputs

#### **General Description**

The LCX16652 contains sixteen non-inverting bidirectional bus transceivers with 3-STATE outputs providing multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to the HIGH logic level. Output Enable pins (OEAB, OEBA) are provided to control the transceiver function (see Functional Description).

The LCX16652 is designed for low-voltage (2.5V or 3.3V)  $V_{CC}$  applications with capability of interfacing to a 5V signal environment.

The LCX16652 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

#### **Features**

- 5V tolerant inputs and outputs
- 2.3V-3.6V V<sub>CC</sub> specifications provided
- 5.7 ns  $t_{PD}$  max ( $V_{CC} = 3.3V$ ), 20  $\mu$ A  $I_{CC}$  max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- $\blacksquare$  ±24 mA output drive (V<sub>CC</sub> = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:

Human body model > 2000V Machine model > 200V

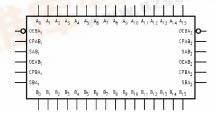
**Note 1:** To ensure the high-impedance state during power up or down,  $\overline{\text{OE}}$  should be tied to  $V_{CC}$  and  $\overline{\text{OE}}$  tied to GND through a resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

## **Ordering Code:**

Order Number	Package Number	Package Description
74LCX16652MEA	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16652MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

## **Logic Symbol**

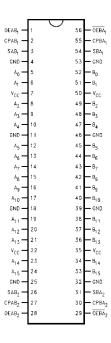


#### **Pin Descriptions**

Pin Names	Description
A <sub>0</sub> -A <sub>15</sub>	Data Register A Inputs/3-STATE Outputs
B <sub>0</sub> -B <sub>15</sub>	Data Register B Inputs/3-STATE Outputs
CPAB <sub>n</sub> , CPBA <sub>n</sub>	Clock Pulse Inputs
SAB <sub>n</sub> , SBA <sub>n</sub>	Select Inputs
$OEAB_n$ , $\overline{OEBA}_n$	Output Enable Inputs



# **Connection Diagram**



## **Truth Table**

(Note 2)

	Inputs			Inputs	/Outputs	On anatin n Maria		
OEAB	OEBA <sub>1</sub>	CPAB <sub>1</sub>	CPBA <sub>1</sub>	SAB <sub>1</sub>	SBA <sub>1</sub>	A <sub>0</sub> thru A <sub>7</sub>	B <sub>0</sub> thru B <sub>7</sub>	Operating Mode
L	Н	H or L	H or L	X	Х	Input	Input	Isolation
L	Н	\	~	Х	Х			Store A and B Data
Х	Н	\	H or L	X	X	Input	Not Specified	Store A, Hold B
Н	Н	\	~	Х	Х	Input	Output	Store A in Both Registers
L	Х	H or L	~	Х	Х	Not Specified	Input	Hold A, Store B
L	L	\		X	Х	Output	Input	Store B in Both Registers
L	L	Х	Х	Х	L	Output	Input	Real-Time B Data to A Bus
L	L	Х	H or L	Х	Н	]		Store B Data to A Bus
Н	Н	Х	Х	L	Х	Input	Output	Real-Time A Data to B Bus
Н	Н	H or L	Х	Н	Х	]		Stored A Data to B Bus
Н	L	H or L	H or L	Н	Н	Output	Output	Stored A Data to B Bus and
								Stored B Data to A Bus

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial

Note 2: The data output functions may be enabled or disabled by various signals at OEAB or OEBA inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW-to-HIGH transition on the clock inputs. This also applies to data I/O (A and B: 8–15) and #2 control pins.

<sup>∠ =</sup> LOW-to-HIGH Clock Transition

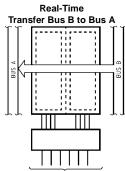
#### **Functional Description**

In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both.

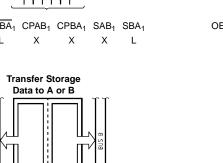
The select ( $SAB_n$ ,  $SBA_n$ ) controls can multiplex stored and

The examples below demonstrate the four fundamental bus-management functions that can be performed with the 74LCX16652.

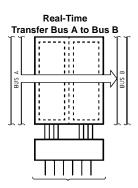
Data on the A or B data bus, or both can be stored in the internal D flip-flop by LOW-to-HIGH transitions at the appropriate Clock Inputs (CPAB $_{\rm n}$ , CPBA $_{\rm n}$ ) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D flip-flops by simultaneously enabling OEAB<sub>n</sub> and OEBA<sub>n</sub>. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.



OEAB<sub>1</sub> OEBA<sub>1</sub> CPAB<sub>1</sub> CPBA<sub>1</sub> SAB<sub>1</sub> SBA<sub>1</sub>

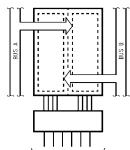


OEAB<sub>1</sub> OEBA<sub>1</sub> CPAB<sub>1</sub> CPBA<sub>1</sub> SAB<sub>1</sub> SBA<sub>1</sub> HorL HorL

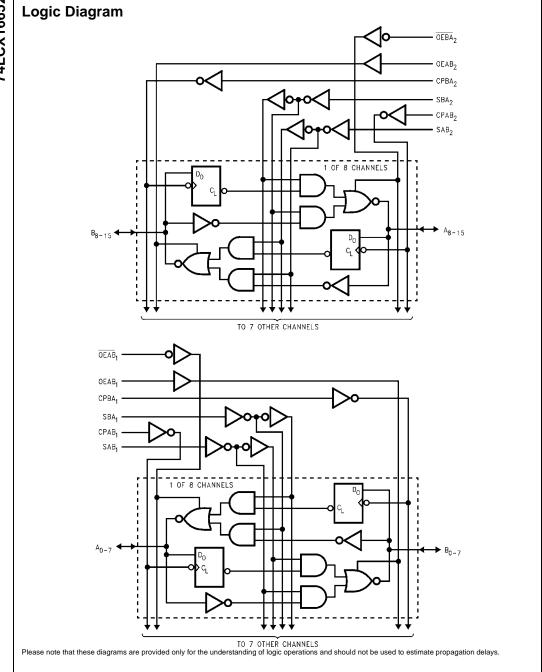


OEAB<sub>1</sub> OEBA<sub>1</sub> CPAB<sub>1</sub> CPBA<sub>1</sub> SAB<sub>1</sub> SBA<sub>1</sub> Н Χ

## Storage



OEAB<sub>1</sub> OEBA<sub>1</sub> CPAB<sub>1</sub> CPBA<sub>1</sub> SAB<sub>1</sub> SBA<sub>1</sub> Χ Н Χ Χ L Χ Χ Χ Н Χ Χ



Absolute Maximum Ratings(Note 3)							
Symbol	Parameter	Value	Conditions	Units			
V <sub>CC</sub>	Supply Voltage	-0.5 to +7.0		V			
VI	DC Input Voltage	−0.5 to +7.0		V			
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V			
		$-0.5$ to $V_{CC} + 0.5$	Output in HIGH or LOW State (Note 4)	l v			
I <sub>IK</sub>	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA			
I <sub>OK</sub>	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA			
		+50	V <sub>O</sub> > V <sub>CC</sub>	IIIA			
Io	DC Output Source/Sink Current	±50		mA			
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100		mA			
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100		mA			
T <sub>STG</sub>	Storage Temperature	-65 to +150		°C			

# **Recommended Operating Conditions** (Note 5)

Symbol	Parameter			Max	Units
V <sub>CC</sub>	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	v
V <sub>I</sub>	Input Voltage		0	5.5	V
Vo	Output Voltage	HIGH or LOW State	0	V <sub>CC</sub>	V
		3-STATE	0	5.5	v
I <sub>OH</sub> /I <sub>OL</sub>	Output Current	$V_{CC} = 3.0V - 3.6V$		±24	
		$V_{CC} = 3.0V - 3.6V$ $V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$		±12	mA
		$V_{CC} = 2.3V - 2.7V$		±8	
T <sub>A</sub>	Free-Air Operating Temperature		-40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V <sub>IN</sub> = 0.8V–2.0V, V <sub>CC</sub> = 3.0V		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: Unused (inputs or I/O's) must be held HIGH or LOW. They may not float.

## **DC Electrical Characteristics**

Symbol	Parameter	Conditions	V <sub>CC</sub>	$T_A = -40^{\circ}C$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	
Symbol		Conditions	(V)	Min	Max	Units
$V_{IH}$	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		V
$V_{IL}$	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 - 3.6		0.8	V
V <sub>OH</sub>	HIGH Level Output Voltage	$I_{OH} = -100 \mu\text{A}$	2.3 – 3.6	V <sub>CC</sub> - 0.2		
		$I_{OH} = -8 \text{ mA}$	2.3	1.8		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		$I_{OH} = -18 \text{ mA}$	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	2.3 – 3.6		0.2	
		I <sub>OL</sub> = 8 mA	2.3		0.6	
		I <sub>OL</sub> = 12 mA	2.7		0.4	V
		I <sub>OL</sub> = 16 mA	3.0		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.55	
I <sub>I</sub>	Input Leakage Current	0 ≤ V <sub>I</sub> ≤ 5.5V	2.3 – 3.6		±5.0	μΑ
l <sub>OZ</sub>	3-STATE I/O Leakage	$0 \le V_O \le 5.5V$	2.3 – 3.6		±5.0	μΑ
		$V_I = V_{IH}$ or $V_{IL}$				μΑ
I <sub>OFF</sub>	Power-Off Leakage Current	$V_I$ or $V_O = 5.5V$	0		10	μΑ

Note 4:  $I_O$  Absolute Maximum Rating must be observed.

## DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> = -40°0	C to +85°C	Units
Cymbol	i didilicio	Conditions	(V)	Min	Max	Ointo
I <sub>CC</sub>	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	цΑ
		3.6V ≤ V <sub>I</sub> , V <sub>O</sub> ≤ 5.5V (Note 6)	2.3 – 3.6		±20	μΛ
$\Delta I_{CC}$	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μΑ

Note 6: Outputs disabled or 3-STATE only.

## **AC Electrical Characteristics**

	Parameter		$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, R_L = 500\Omega$					
Symbol		V <sub>CC</sub> = 3.	3V ± 0.3V	V <sub>CC</sub>	= 2.7V	V <sub>CC</sub> = 2.	5V ± 0.2V	Units
Symbol	r al allietei	C <sub>L</sub> =	50 pF	C <sub>L</sub> = 50 pF		C <sub>L</sub> = 30 pF		Units
		Min	Max	Min	Max	Min	Max	
f <sub>MAX</sub>	Maximum Clock Frequency	170						MHz
t <sub>PHL</sub>	Propagation Delay	1.5	5.7	1.5	6.2	1.5	6.8	ns
t <sub>PLH</sub>	Bus to Bus	1.5	5.7	1.5	6.2	1.5	6.8	115
t <sub>PHL</sub>	Propagation Delay	1.5	6.2	1.5	7.0	1.5	7.4	
t <sub>PLH</sub>	Clock to Bus	1.5	6.2	1.5	7.0	1.5	7.4	ns
t <sub>PHL</sub>	Propagation Delay	1.5	6.5	1.5	7.0	1.5	7.8	
t <sub>PLH</sub>	Select to Bus	1.5	6.5	1.5	7.0	1.5	7.8	ns
t <sub>PZL</sub>	Output Enable Time	1.5	7.0	1.5	8.0	1.5	9.1	ns
t <sub>PZH</sub>		1.5	7.0	1.5	8.0	1.5	9.1	115
t <sub>PLZ</sub>	Output Disable Time	1.5	6.5	1.5	7.0	1.5	7.8	
t <sub>PHZ</sub>		1.5	6.5	1.5	7.0	1.5	7.8	ns
t <sub>S</sub>	Setup Time	2.5		2.5		3.0		ns
t <sub>H</sub>	Hold Time	1.5		1.5		2.0		ns
t <sub>W</sub>	Pulse Width	3.0		3.0		3.5		ns
toshl	Output to Output Skew (Note 7)		1.0					ns
t <sub>OSLH</sub>			1.0					115

Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>). Parameter guaranteed by design.

## **Dynamic Switching Characteristics**

Symbol	Parameter	Conditions	V <sub>CC</sub>	T <sub>A</sub> = 25°C	Units
V <sub>OLP</sub>	Quiet Output Dynamic Peak V <sub>OL</sub>	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
		$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	0.6	V
V <sub>OLV</sub>	Quiet Output Dynamic Valley V <sub>OL</sub>	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	-0.6	V

## Capacitance

Symbol	Parameter	Conditions	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C <sub>I/O</sub>	Input/Output Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$ , $f = 10$ MHz	20	pF

## AC LOADING and WAVEFORMS Generic for LCX Family

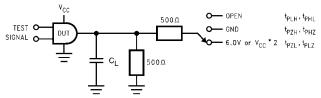
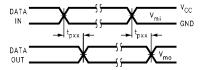
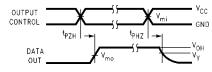


FIGURE 1. AC Test Circuit ( $C_L$  includes probe and jig capacitance)

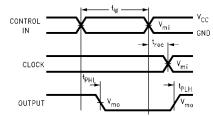
Test	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PZL</sub> , t <sub>PLZ</sub>	6V at $V_{CC} = 3.3 \pm 0.3V$ $V_{CC}$ x 2 at $V_{CC} = 2.5 \pm 0.2V$
$t_{PZH}, t_{PHZ}$	GND



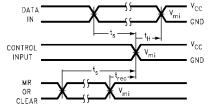
**Waveform for Inverting and Non-Inverting Functions** 



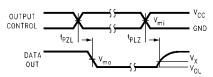
3-STATE Output High Enable and Disable Times for Logic



Propagation Delay. Pulse Width and  $t_{\text{rec}}$  Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

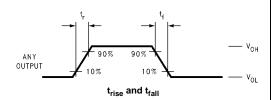
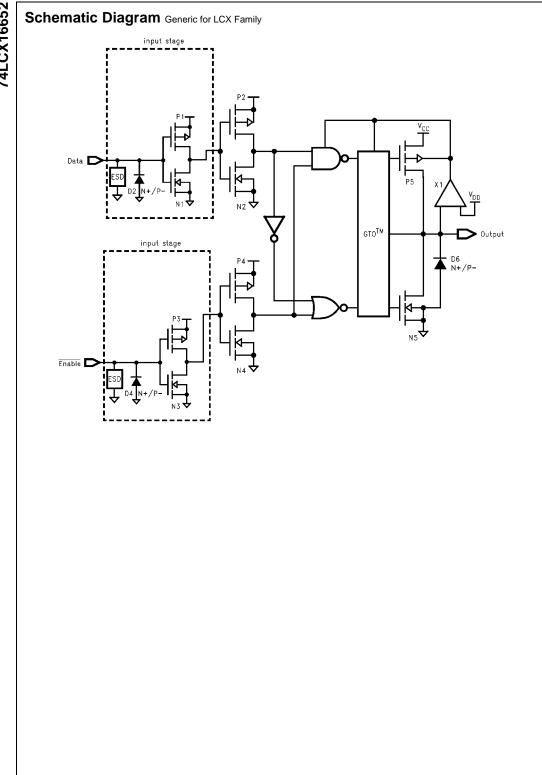
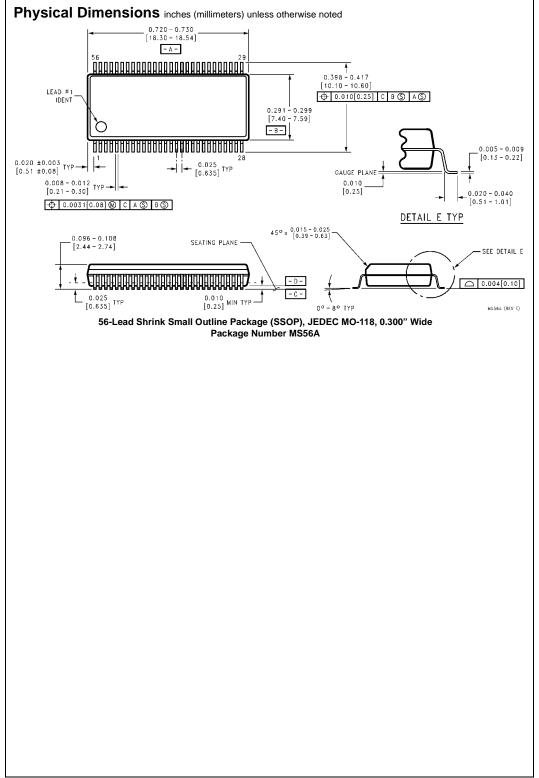
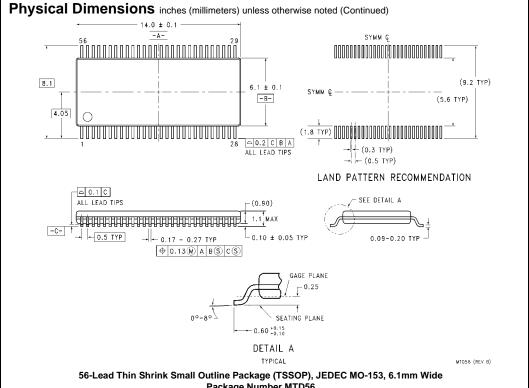


FIGURE 2. Waveforms (Input Characteristics; f = 1MHz,  $t_R = t_F = 3ns$ )

Symbol	V <sub>cc</sub>					
Cymbol	$3.3V \pm 0.3V$	2.7V	2.5V ± 0.2V			
V <sub>mi</sub>	1.5V	1.5V	V <sub>CC</sub> /2			
$V_{mo}$	1.5V	1.5V	V <sub>CC</sub> /2			
V <sub>x</sub>	V <sub>OL</sub> + 0.3V	V <sub>OL</sub> + 0.3V	V <sub>OL</sub> + 0.15V			
V <sub>y</sub>	V <sub>OH</sub> – 0.3V	V <sub>OH</sub> – 0.3V	V <sub>OH</sub> – 0.15V			







Package Number MTD56

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